

ZHEJIANG UNIU-NE Technology CO., LTD 浙江宇力微新能源科技有限公司



V 1.0

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100V Input,2A, Switching Current Limit Step-Down Converter **General Description Key Features**

The U3502 is a high-voltage, stepdown, switching regulator that delivers up to 2A of max current to the load. It integrates a high-side, high-voltage, power MOSFET with a current limit of 5A, typically. The wide 10V to 100V input range accommodates a variety of stepdown applications, making it ideal for automotive, industry, and lighting applications. Hysteretic voltage-mode control is employed for very fast response. UNI's proprietary feedback control scheme minimizes the number of required external components.

The switching frequency is 120KHz, allowing for small component size. Thermal shutdown and short-circuit protection (SCP) provide reliable and faulttolerant operations. Low quiescent current allows the U3502 to be used in batterypowered applications.

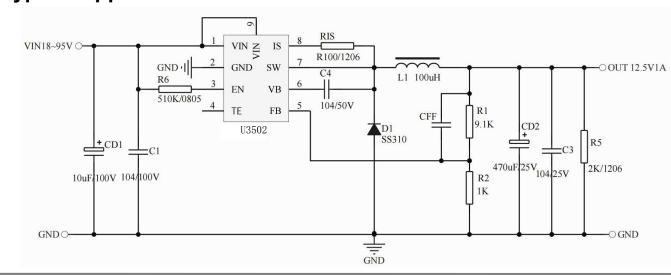
The U3502 is available in а ESOP-8 package with an exposed pad.

The U3502 can cooperate with MCU to test VIN voltage(TE PIN), control internal logic shutdown and realize zero power consumption.

- Wide 10V to 100V Input Range
- Built-In 100V/5A Typical Peak Switching Current Limit
- Built-in Bootstrap Diode
- Hysteretic Control: No Compensation
- 120KHz Switching Frequency
- PWM Dimming Control Input for step-• down Application
- Short-Circuit Protection (SCP) with Integrated High-Side MOSFET
- Low Quiescent Current
- Thermal Shutdown
- Available in a ESOP-8 Package with an Exposed Pad

APPLICATIONS

- Scooters, E-Bike Control Power Supplies
- Solar Energy Systems
- Automotive System Power
- Industrial Power Supplies
- **High-Power LED Drivers**
- USB



Typical Application

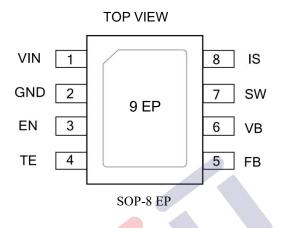


Ordering Information

Part Number	Package	Rdson	Vo	VINMAX	Load Current	Description
U3502	ESOP-8	96mΩ	>2V	100V	lo<=2500mA	4000Pcs/Reel

*For Tape & Reel, add suffix –Z (e.g. U3502–Z)

Pin Description



Pin Functions

SOP-8 EP Pin #	Name	Description		
1	VIN	Input supply. VIN supplies power toallofthe internal control circuitries, both BST regulators, and the high-side switch. A decoupling capacitor to ground must be placed close to VIN to minimizeswitchingspikes.		
2	GND	Ground. GND should beplaced asclose to the output capacitor aspossible to avoid the high-currentswitchpaths. Connect the exposed padto GND plane for optimal thermal performance.		
3	EN	Enable input. Pull EN below the specified threshold to shut down the U3502. Pull EN above the specified threshold or leave EN floating to enable the U3502.		
4	TE	Test VIN voltage(TE PIN). control internal logic shutdown and realize zero power consumption. The ratio of pull-up resistance to pull-down resistance is about 30/1.		
5	FB	Feedback. FB is the input to the voltage hysteretic comparators. The average FB voltage is maintained at 200mV by loop regulation.		
6	VB	Boot. BST is the positive power supply for the internal, floating, high-side MOSFET driver. Connect a bypass capacitor between BST and SW.		
7	SW	Switch node. SW is the output from the high-side switch. A low forward voltage Schottky rectifier to ground is required. The rectifier must be placed close to SW to reduce switching spikes.		
8	IS	Current detection. Current Sensing Input.		
9	EP	Input supply. VIN supplies power to all of the internal control circuitries , both BST regulators , and the high-side switch . A decoupling capacitor to ground must be placed close to VIN to minimizes witchingspikes.		

Block Diagram

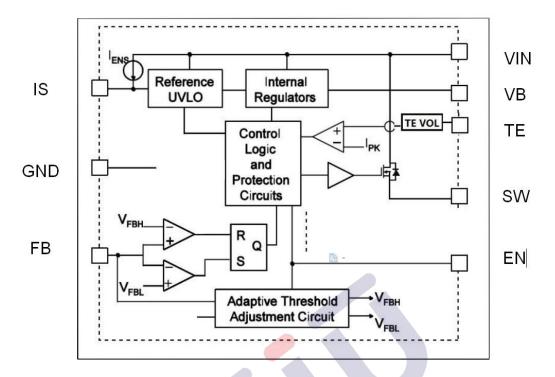


Figure 1: Function Block Diagram

Absolute Maximum Ratings (Note 1)

Parameter	Value	Unit
VIN,SW Pin Voltage Range	-0.3 to 120	V
VB Supply Voltage	120+7	V
VB Clamp Current	1	mA
FB, IS, EN Voltage Range	-0.3 to 7	V
Package Thermal ResistanceJunction to Ambient (ESOP-8)	165	°C/W
Maximum Junction Temperature	160	°C
Storage Temperature Range	-65 to 150	°C
Lead Temperature (Soldering, 10sec.)	260	°C
ESD Capability, HBM (Human Body Model)	3	kV
ESD Capability, MM (Machine Model)	250	V



ELECTRICAL CHARACTERISTICS

 V_{IN} = 60V, T_A = +25°C, unless otherwise noted. Specifications over temperature are guaranteed by design and characterization.

Parameter	Symbol	Condition	Min	Тур	Мах	Units
VIN UVLO threshold			_	10.0		V
VIN UVLO hysteresis			_	0.4		V
Shutdown supply current		V _{EN} = 0V	_	1.8		μA
Quiescent supply current		No load, DIM = low, V _{FB} = 1.25V	_	300	_	μA
Upper switch on resistance	R _{DS(ON)}	V _{BST} - V _{SW} = 5V	_	150	_	mΩ
Upper switch leakage current	I _{SWLK}	$V_{EN} = 0V, V_{SW} = 0V$	_	0.02	1.5	μA
Current limit	I _{PK}	V _{FB} = 1.25V	—	3.5	—	А
Working frequency	Fsw		_	120	_	KHz
EN -on	V _{ENH}		_	2.8	7	V
EN -off	V _{ENL}		—	_	1	V
EN threshold hysteresis	V _{ENHY}		- (500		mV
EN input current	I _{ENI}	V _{EN} = 5V		0.01	1.5	μA
EN pull-up current	I _{ENS}	V _{EN} = 2V	_	2	3	μA
Feedback voltage threshold	V _{FBH}		1.22	1.25	1.28	V
FB input current	I _{FB}	V _{FB} = 5V or 0V	-800	_	800	nA
FB propagation delay to output high	T _{FBDH}	Falling edge of V _{FB} from1.25V to 0V to V _{SW} rising edge	_	100	_	ns
FB propagation delay to output high	T _{FBDL}	Rising edge of V _{FB} from 0V to 1.25V to V _{SW} falling edge		100		ns
Thermal shutdown		Trigger thermal shutdown		150	_	С
		Hysteresis	_	20		

NOTES:

Note1. Stresses listed as the above "Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to maximum rating conditions for extended periods may remain possibility to affect device reliability.

Note2. The device is not guaranteed to function outside its operating conditions.

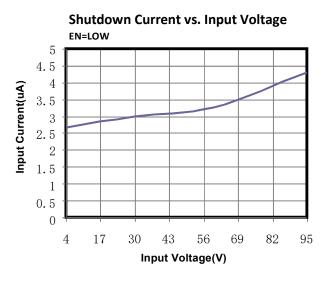
Note3. Guaranteed by design.

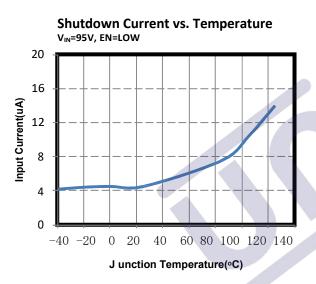


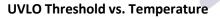
U3502

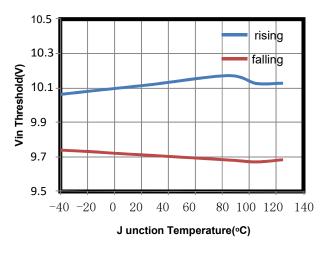
Typical Characteristics

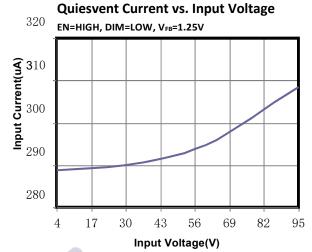
 V_{IN} = 60V, T_{A} = +25°C, unless otherwise noted.



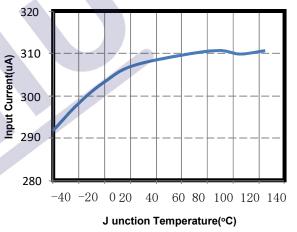


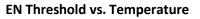


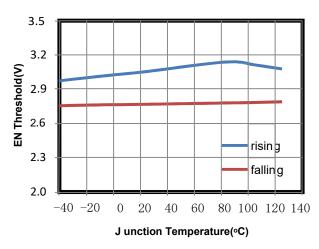




Quiescent Current vs. Temperature VIN=95V, DIM=LOW,EN=HIGH,VFB=250mV





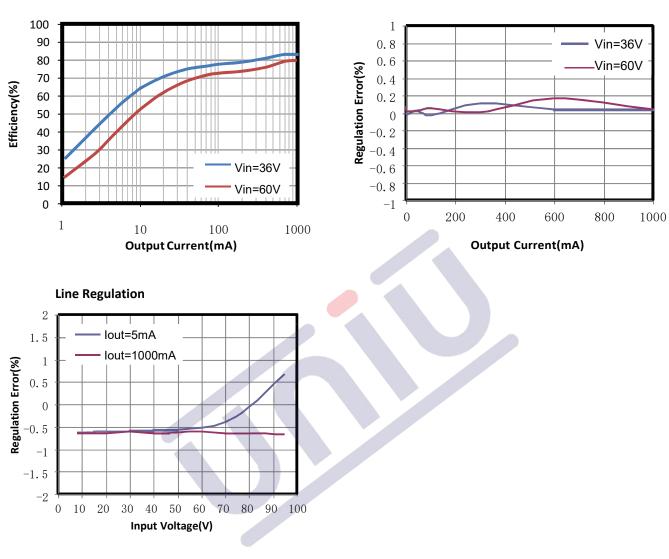




Load Regulation

Typical Performance Characteristics

 V_{IN} = 60V, V_{OUT} = 12V, I_{OUT} = 1A, L = 47µH, C_{OUT} = 100µF, T_A = +25°C, unless otherwise noted.



Efficiency vs. Output Current



Operation

Hysteresis Current Control with Adaptive Threshold Adjustment

The U3502 operates in a hysteretic voltagecontrol mode to regulate the output voltage. FB is connected to the tap of a resistor divider, which determines the output voltage. The power MOSFET is turned on when the FB voltage (V_{FB}) rises to FBon and remains on until V_{FB} rises to FBoff. The power MOSFET is turned off when V_{FB} drops to FBoff and remains off until V_{FB} falls to FBon. The two thresholds of FBon and FBoff are adjusted adaptively to compensate for all the circuit delays, so the output voltage is regulated with an average 1.25V value at FB.

Enable (EN) Control

The U3502 has a dedicated enable control pin (EN) with positive logic. Its falling threshold is 2.5V, and its rising threshold is 2.8V. When EN is pulled up to about 3V by an internal current source, so it is enabled.

Floating Driver and Bootstrap Charging

The floating power MOSFET driver is powered by an external bootstrap capacitor. This floating driver has its own under-voltage lockout (UVLO) protection. The UVLO rising threshold is 10V with a threshold error of 0.2V.

The bootstrap capacitor is charged and regulated to about 5V by the dedicated internal bootstrap regulator.

If the internal circuit does not have sufficient voltage, and the bootstrap capacitor is not sufficiently charged, extra external circuitry can be used to ensure that the bootstrap voltage is in the normal operating region. Refer to the External Bootstrap Diode section for more details.

Under-Voltage Lockout (UVLO)

Under-voltage lockout (UVLO) is implemented to protect the chip from operating at an insufficient supply voltage. The UVLO rising threshold is about 10V, while its falling threshold is a consistent 9.5V.

Fast charging Function for USB Applications

Because the FB reference of the U3502 is very flexible, it is recommended to use the U3502 for USB Fast charging Applications by connecting the current sense resistor between FB and GND.

Thermal Shutdown

Thermal shutdown is implemented to prevent the chip from operating at exceedingly high temperatures. When the silicon die temperature is higher than its upper threshold, the entire chip shuts down. When the temperature is lower than its lower threshold, the chip is enabled again.

Output Short Protection

The output voltage is well-regulated when VFB is around 1.25V. If the output is pulled low in overcurrent protection (OCP) or is shorted to GND directly, V_{FB} is low, even though the power MOSFET is turned on. The U3502 regards the low V_{FB} as a failure. The power MOSFET shuts off if the failure time is longer than 10µs. The U3502 attempts operation again after a delay of about 300µs.

The power MOSFET current is also accurately sensed via a current sense MOSFET. If the current is over the current limit, the IC is shut down. This offers extra protection under outputshort conditions.

Application Information

Setting the Output Voltage

The output voltage (V_{OUT}) is set by a resistor divider (R1 and R2) (see the Typical Application on page 1). To achieve good noise immunity and low power loss, R2 is recommended to be in the range of $1k\Omega$ to $50k\Omega$. R1 can then be determined with Equation (1):

$$R1 = \frac{V_{OUT} - V_{FB}}{V_{FB}} \times R2 \tag{1}$$

Where V_{FB} is 1.25V, typically.

Output Capacitor and Frequency Setting

The output capacitor (COUT) is necessary for achieving a smooth output voltage. The ESR of the capacitor should be sufficiently large compared to the capacitance; otherwise, the system may behave in an unexpected way, and the current ripple may be very high.V_{FB} changes from 1.22V to 1.28V when the power MOSFET switches on. To charge the capacitor and generate 1.28V at FB, the system needs ESR and some inductor current. For example, for a 5V V_{OUT} , if the forward capacitor is 0.1 μ F, the suggested ESR range of the output capacitor is $100m\Omega$ to $250m\Omega$. Tantalum or aluminum electrolytic capacitors with a small ceramic capacitor are recommended.

A forward capacitor across R1 is recommended when the output capacitor is tantalum or aluminum electrolytic, which can set the desired frequency if the output capacitor and ESR cannot be changed. The forward capacitor can reduce the output voltage ripple.

In some application, simply a forward capacitor may not get proper frequency, then we can add a forward resistor in series with the forward capacitor or even more add a ceramic on the output.

Selecting the Inductor

The inductor (L) is required to convert the switching voltage to a smooth current to the load. Although the output current is low, it is

recommended that the inductor current be continuous in each switching period to prevent reaching the current limit. Calculate the inductor value with Equation (2):

$$L = \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{F_{SW} \times I_{OUT} \times V_{IN} \times K}$$
(2)

Where K is a coefficient of about 0. $15 \sim 0.85$

Output Rectifier Diode

The output rectifier diode supplies current to the inductor when the high-side switch is off. To reduce losses due to the diode forward voltage and recovery times, use a Schottky diode. The average current through the diode can be approximated with Equation (3):

$$I_D = I_{OUT} \times (1 - \frac{V_{OUT}}{V_{IN}})$$
(3)

Choose a diode with a maximum reverse voltage rating greater than the maximum input voltage and a current rating is greater than the average diode current.

Input Capacitor (CIN)

The input current to the step-down converter is discontinuous and therefore requires a capacitor to supply AC current to the step-down converter while maintaining the DC input voltage. Use low ESR capacitors for the best performance, especially under high switching frequency applications.

The RMS current through the input capacitor can be calculated with Equation (4):

$$I_{IN_{AC}} = I_{OUT} \times \sqrt{\frac{V_{OUT}}{V_{IN}} \times (1 - \frac{V_{OUT}}{V_{IN}})}$$
(4)

With low ESR capacitors, the input voltage ripple can be estimated with Equation (5):

$$\Delta V_{IN} = \frac{I_{OUT} \times V_{OUT}}{F_{SW} \times C_{IN} \times V_{IN}} \times (1 - \frac{V_{OUT}}{V_{IN}})$$
(5)

Choose an input capacitor with enough RMS current rating and enough capacitance for small input voltage ripples.

When electrolytic or tantalum capacitors are applied, a small, high-quality ceramic capacitor (i.e.: 0. 1μ F) should be placed as close to the IC as possible.



External Bootstrap Diode

An external bootstrap diode may enhance the efficiency of the converter (see Figure 2).

The bootstrap diode can be a low-cost one,

Optimize circuit structure, save cost, and reduce error rate for peripheral circuit configuration.

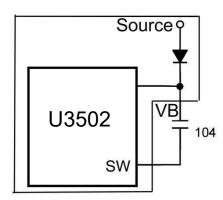


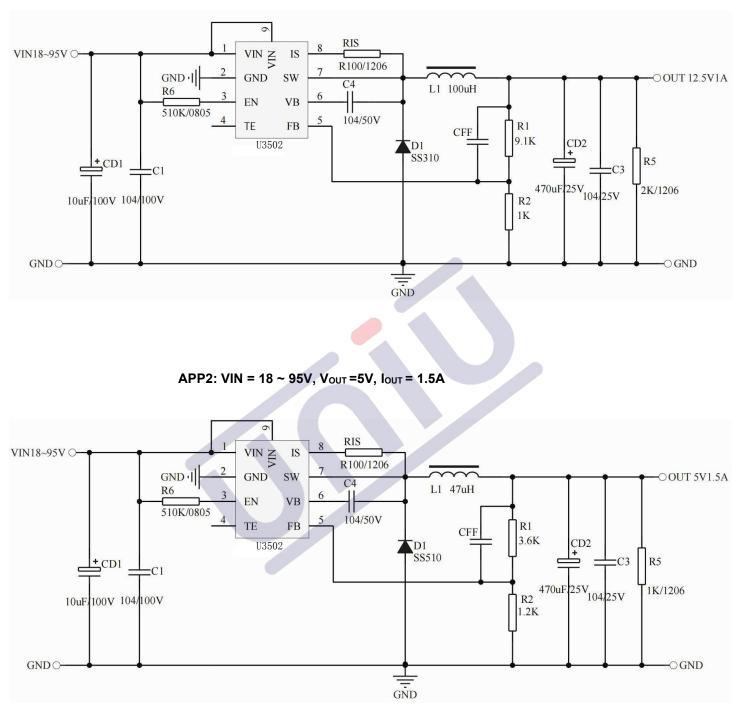
Figure 2: External Bootstrap Diode

PCB Layout Guidelines

Efficient PCB layout is critical for stable operation. For best results, refer to Figure 3 and follow the guidelines below.

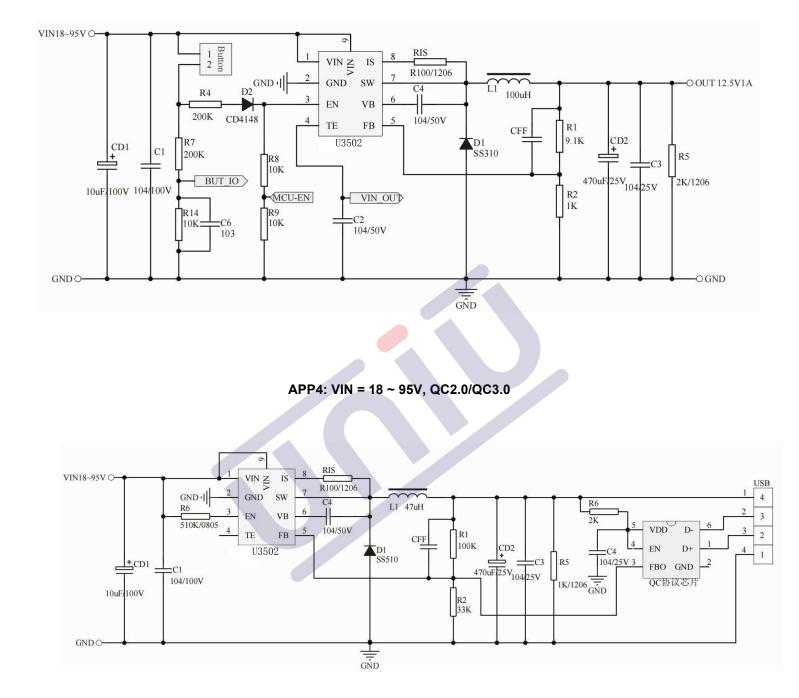
- 1. Place the input decoupling capacitor, catch diode, and the U3502 (VIN, SW, and PGND) as close to each other as possible.
- Keep the power traces very short and fairly wide, especially for the SW node. This can help greatly reduce voltage spikes on the SW node and lower the EMI noise level.
- 3. Run the feedback trace as far from the inductor and noisy power traces (like the SW node) as possible.
- 4. Place thermal vias with 15mil barrel diameter and 40mil pitch (distance between the centers) under the exposed pad to improve thermal conduction.

Typical Application Circuit



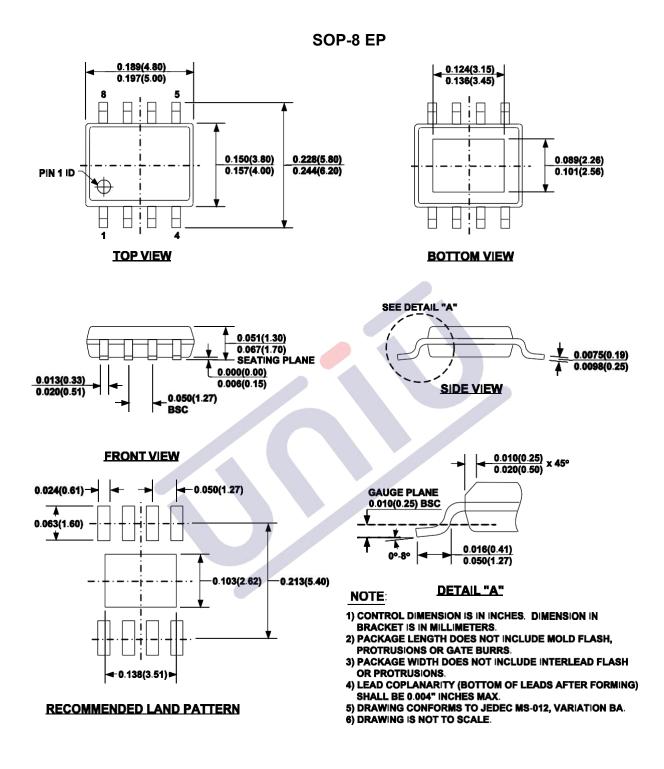
APP1: VIN = 18 ~ 95V, Vout = 12.5V, Iout = 1A





APP3: VIN = 18 ~ 95V, Vout = 12.5V, Iout = 1A(TE PIN zero power consumption)

Package Information



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1.版本记录

DATE	REV.	DESCRIPTION
2018/02/16	1.0	First Release
2018/03/18	2.0	Package is changed to SOP-8
2019/05/20	3.0	Package is changed to ESOP-8
2019/10/15	3.1	Pin definition changed
2019/11/09	3.2	Add typical application circuits
2021/12/20	3.3	Delete CSM3502E
2022/04/08	1.0	Rename CSM3502 to U3502

2.免责声明

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浙江宇力微新能源科技有限公司 总部地址:绍兴市越城区斗门街道袍渎路25号中节能科创园45幢4/5楼 电话:0575-85087896 (研发部) 传真:0575-88125157 E-mail:htw@uni-semic.com

无锡地址:无锡市新吴区纺城大道299号深港都会广场9-1401 电话:0510-85297939 E-mail:zh@uni-semic.com

深圳地址:深圳市宝安区航城街道三围社区南昌路上合工业园B2栋501 电话:0755-84510976 E-mail: htw@uni-semic.com

